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FORM PTO 1449 Modified  APR 1 8 2002	Sheet 1 of 1			
List of Patents and Publications				
(Use several sheets if necessary)	Docket No. BTG-10002	Serial No. 09/137,084		
U.S. Department of Commerce		ŧ,	TECH!	)
Patent and Trademark Office	Applicant		早海	<b>つ</b>
	Michael F. Stumborg,	et al.	22	17
	Filing Date August 20, 1998		Group-281B	; ; ; ; ; ; ; ; ; ; ; ; ; ; ; ; ; ; ;

		OCUMENTS				
Examine Initial		Document No.	Date	Name	Class	
Vn	AA	4,291,327	Sep-81	Tsang		Subclass
	AB	4,550,331		Milano	357	
	AC	4,692,993		Clark, et al	357	
·	AD	4,765,845	1	Takada, et al	437	
	AE	4,847,666		Heremans, et al.	136	
	AF	5,124,762		Childs, et al	357	1
	AG	5,225,031		Mckee, et al	357	1
	AH	5,248,633		Morar, et al	156	61
	AI	5,285,079		Tsukamoto, et al.	437	19
	AJ	5,378,905		Nakamura	257	1
	AK	5,391,517			257	21
	AL	5,435,264		Gelatos, et al	437	19
	AM		ľ	Santiago, et al	117	92
+	AN	5,482,003		Mckee, et al	117	108
_	AO	5,593,951	Jan97 I		505	235
_	AP	5,677,572		lung, et al.	257	750
	AQ	5,690,737		Santiago, et al.	117	92
+-	AR	5,753,040	May-98 (		117	106
+	AS	5,695,810		Oubin, et al.	427	96
+	AT	5,773,359	1 -	Aitchell, et al	438	614
	AU	5,824,599	Oct98 S	chacham-Diamond et al.	437	230
Vn	AV	5,932,006	Aug99S	antiago, et al.	117	92
AMINE	1 1	5,962,921	Sep99 G	ardner, et al.	257	751
- TATTIAL	-11			DATE CONSIDERED		

HUNG K. VU

06/30/03

FORM PTO-1249 Modified	Sheet 2 of 2	
List of Patents and Publications Cited by Application (Use several sheets if necessary)	Docket No. BTG-10002	Serial No. 09/137,084
U.S. Department of Commerce Patent and Trademark Office	Applicant Michael F. Stumborg	g, et al.
•	Filing Date August 20, 1998	Group 2811
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O T TIE	OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages etc.)						Translati
		Document	Date	Country	Class	Subclass	on
Vin	BA.	2-255569	10/31/90	Japan			Full text
Other	Docume	nts (Including Aut	hor, Title, I	Oate, Pertinent P	ages, Etc.	.)	
,	BB	Chaudhari, et al., "					
<u>Vu</u>		insulator-semiconductor application", Appl. Phys. Let., Vol 62,No.8 22 Feb 1993 pp852-854					
1	BC	Chu et al., "Hetero	•	<b>U</b> 1	fluorides o	on gallium a	arsenide"
		Mat Sci and Eng. E			(001	1.0	N A 33 T
	BD	Clemens et al., Growth of BaF2 and BaF2SrF2 layers on (001) oriented GaAs" J Appl. Phys. Vol 66 No 4 15 Aug. 1089 pp1680-1685					
	BE	Hung et al., "Epitaxial growth of alkaline earth fluoride films on HF-treated Si and					
		(NH4) 2Sx Treated GaAs without in situ cleaning" Appl Phys Lett., Vol 60, No. 2 13 Jan 1992 pp201-203					
	BF	S.M. Sze, "Semiconductors Devices Physics and Technology" 1985 pp208-					
		210					
	BG						
ł		on Si(100) by target angle dependence on RBS yields" Nucl. Instru and					
<u> </u>		methods in Physics Res. B, Vol 95 1995 pp319-392					
.(	BH Stumborg et al., "Surface chemical state population in molecular beam						
Vn	epitaxy deposition of BaF2 on GaAs by X-ray photoelectron spectroscopy						
	and heavy-ion backscattering spectroscopy" J. Vac Sic. Technol., Vol 14 No						
1. Jan/Feb 1996 pp2739-2744							
EXAM	EXAMINER HUNGE K. NU DATE CONSIDERED 06/30/03						

FORM PTO 1449 Modified  APR 1 8 2002  List of Patents and Publications	Sheet 3 of 3	
Cited by Applicant (Use several sheets if necessary)	Docket No. BTG-10002	Serial No. 09/137,084
U.S. Department of Commerce		
Patent and Trademark Office	Applicant Michael F. Stumborg	g, et al.
	Filing Date August 20, 1998	Group 2811

<u>V_</u>	CA	Stumborg et al., "Growth and interfacial chemistry of insulating (100) barium fluoride on gallium areside" <u>J Apppl. Phys</u> , Vol 77, No. 6 Mar 15 1995 pp 2739-2744
1/2	СВ	Truscott et al., "MCE Growth of BaF2/(Ga,In)(As,Sb) Structures" <u>Journal of</u> Crystal Growth, Vol 81 (1987) pp552-556
L.	CC	Colbow et al., "Photoemisison study of the formation of SrF2/GaAs(100) and BaF2/GaAs(100) interfaces" Physical Review B, Vol 49 No. 3, 15 Jan 1994, pp1750-1756
EXAMINER		HUNG K. VU DATE CONSIDERED \$06/30/03

	FORM PTO-1449 Modified		_	
	· · · · · · · · · · · · · · · · · · ·	Sheet 1 of 1		
	List of Patents and Publications			
	Cited by Applicant	Docket No.	Serial No.	
	(Use several sheets if necessary)	BTG-10002	09/137,084	
	U.S. Department of Commerce			
OIP	Patent and Trademark Office	Applicant		
7017	6 501	Michael F. Stumborg	, et al.	
APR 2 8 2	<b>&amp;</b> 00	Filing Date		Group 2811
A TRADEMA	N. O. T.	August 20, 1998		

Other	Docum	ents (Including Author, Title, Date, Pertinent Pages, Etc.)
Y.	AA	Nandan, B., et al., "Stability of Sputter Deposited" Nat. Res. Soc. Symp. Proc., Vol. 250, pgs 929-934 1992
.Vn	AB	Kirchner E., et al., "Ultra Thin Sacrificial Diffusion Barriers – Control of Diffusion Across The Cu-SiO <sub>2</sub> Interface", Mal. Res. Soc. Symp. Proc., Vol. 318, pgs 319-322, 1994
Vu	AC	Murarka, S. "Multilevel Interconnections For ULSI and GSI Era", Materials Science and Engineering, R19, pgs 87-151, 1997
	AD	E C
	AE	
	AF	PR 31
	AG	7. 6
	AH	CENTER
	AI	5 5
	AJ	2800
	AK	0
	AL	
	AM	
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		08/30/03